

# NSR2030DMX

## 2A, 30V Schottky Half Bridge

These half bridge Schottky barrier diodes are designed for the rectification of the high speed signal of wireless charging. The NSR2030DMX has a very low forward voltage that will reduce conduction loss. It is housed in a XDFN 2.0 x 1.35 x 0.4 mm package that is ideal for space constrained wireless applications.

### Features

- Extremely Fast Switching Speed
- Low Forward Voltage – 0.54 V (Typ) @  $I_F = 2$  A
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

### Typical Applications

- Low Voltage Half Bridge Rectification & Wireless Charging

### MAXIMUM RATINGS ( $T_J = 150^\circ\text{C}$ unless otherwise noted) (Note 1)

Rating	Symbol	Value	Unit
Reverse Voltage	$V_R$	30	V
Forward Current (DC)	$I_F$	2.0	A
Forward Current Surge Peak (60 Hz, 1 cycle)	$I_{FSM}$	8.0	A
Non-Repetitive Peak Forward Current (Square Wave, $T_J = 25^\circ\text{C}$ prior to surge) $t = 1 \mu\text{s}$ $t = 1 \text{ ms}$ $t = 1 \text{ s}$	$I_{FSM}$	55 10 5.0	A

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. All specifications pertain to a single diode.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$ (Note 2)	0.634 5.07	W mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$ (Note 2)	197.2	$^\circ\text{C}/\text{W}$
Junction Temperature	$T_J$	+150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$

2. Single Layer JEDEC JESD51.3 FR-4 @ 100 mm<sup>2</sup>, 2 oz. copper trace, still air.



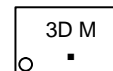
ON Semiconductor®

[www.onsemi.com](http://www.onsemi.com)

### MARKING DIAGRAM

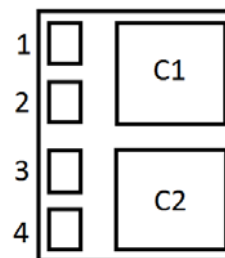


XDFN4 2.0x1.35  
CASE 711BD

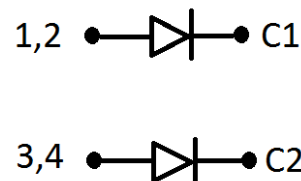


3D = Specific Device Code  
M = Date Code  
■ = Pb-Free Package

### PIN CONNECTIONS



### DEVICE SCHEMATIC



### ORDERING INFORMATION

Device	Package	Shipping†
NSR2030DMXTAG	XDFN4 (Pb-Free)	3000 / Tape & Reel

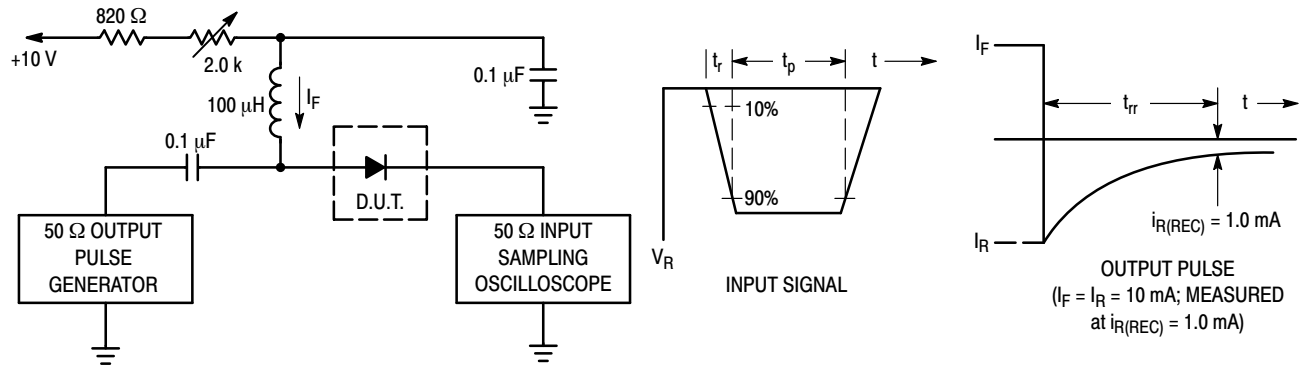
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NSR2030DMX

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (Note 3)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage ( $I_R = 1.0\text{ mA}$ )	$V_{(BR)}$	30	–	–	V
Reverse Leakage ( $V_R = 30\text{ V}$ )	$I_R$	–	5.0	20	$\mu\text{A}$
Forward Voltage ( $I_F = 0.5\text{ A}$ )	$V_F$	–	0.41	0.45	V
Forward Voltage ( $I_F = 1.0\text{ A}$ )	$V_F$	–	0.46	0.55	V
Forward Voltage ( $I_F = 2.0\text{ A}$ )	$V_F$	–	0.54	0.65	V
Reverse Recovery Time ( $I_F = I_R = 10\text{ mA}$ , $I_{R(REC)} = 1.0\text{ mA}$ )	$t_{rr}$	–	25	–	ns
Total Capacitance ( $V_R = 1.0\text{ V}$ , $f = 1.0\text{ MHz}$ )	$C_T$	–	76	–	pF

3. All specifications pertain to a single diode.



- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 10 mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 10 mA.  
 3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**

# NSR2030DMX

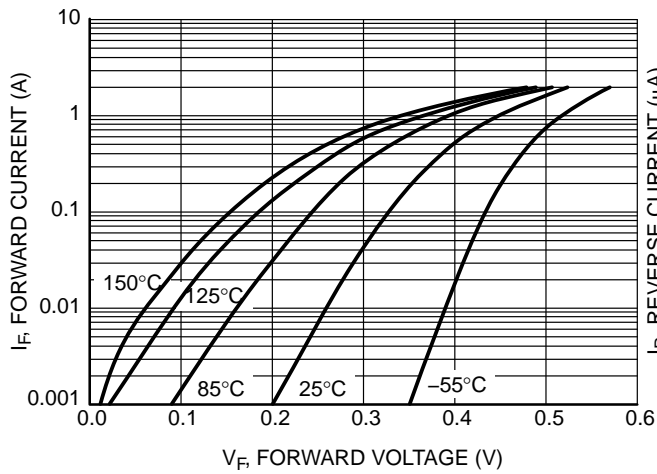


Figure 1. Forward Voltage

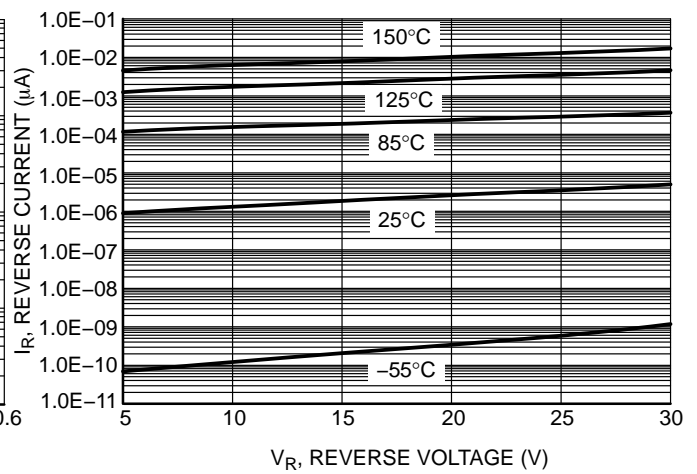


Figure 2. Reverse Leakage

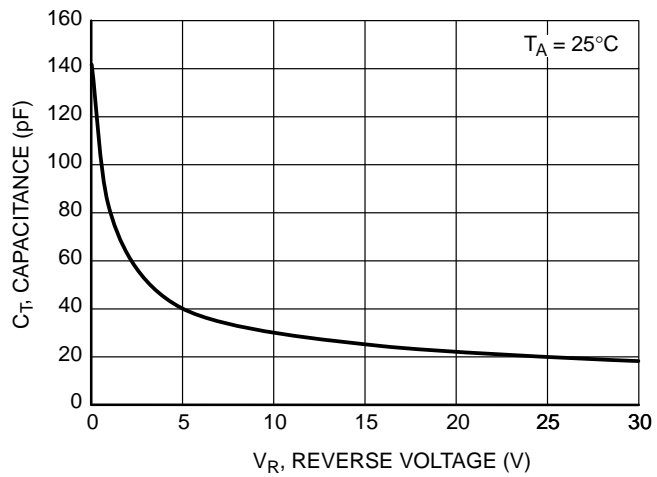


Figure 3. Capacitance

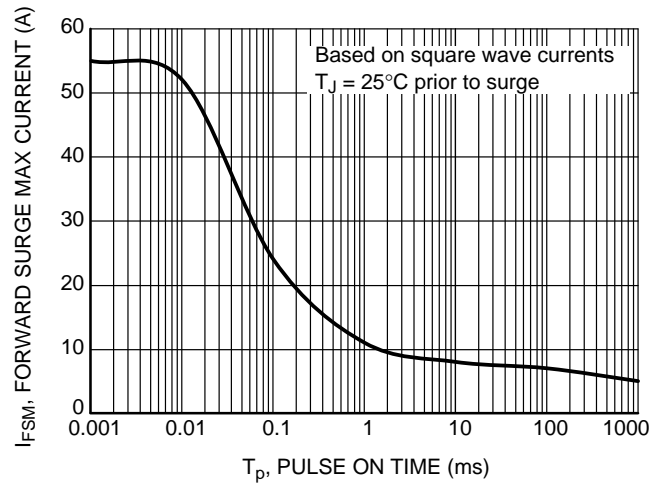


Figure 4. Non-Repetitive Peak Forward Current, Max Values

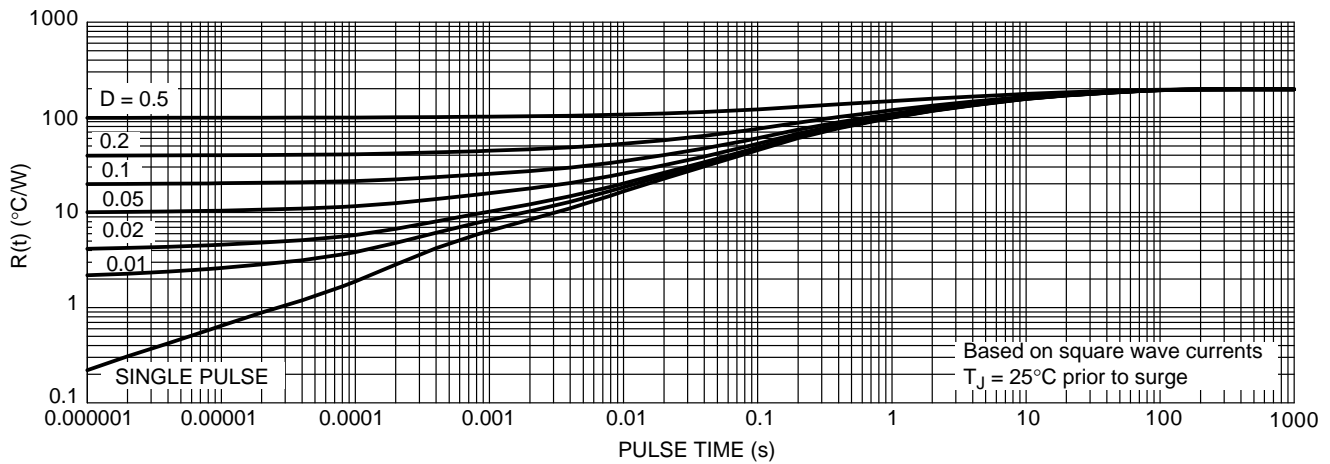


Figure 5. Thermal Response

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

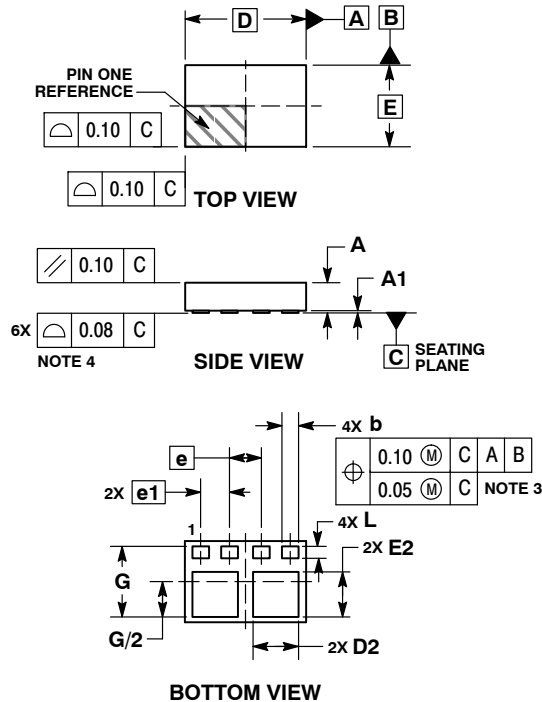
ON Semiconductor®



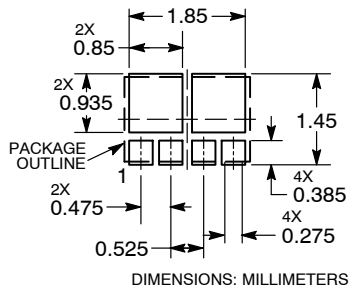
SCALE 4:1

**XDFN4 2.0x1.35, 0.525P**  
CASE 711BD  
ISSUE O

DATE 15 SEP 2015



### RECOMMENDED MOUNTING FOOTPRINT

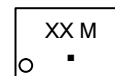


#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.25 MM FROM THE TERMINAL TIP.
4. COPLANARITY APPLIES TO THE PADS AS WELL AS THE TERMINALS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.34	0.44
A1	0.00	0.05
b	0.225	0.325
D	2.00	BSC
D2	0.70	0.80
E	1.35	BSC
E2	0.70	0.80
e	0.525	BSC
e1	0.475	BSC
G	1.12	1.23
L	0.15	0.25

### GENERIC MARKING DIAGRAM\*



XX = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

<b>DOCUMENT NUMBER:</b>	<b>98AON05108G</b>	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
<b>DESCRIPTION:</b>	<b>XDFN4 2.0X1.35, 0.525P</b>	<b>PAGE 1 OF 1</b>

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Email Requests to: [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**onsemi Website:** [www.onsemi.com](http://www.onsemi.com)

### TECHNICAL SUPPORT

**North American Technical Support:**

Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Phone: 011 421 33 790 2910

**Europe, Middle East and Africa Technical Support:**

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative